



High Efficient Rectifier



Features

- High efficiency
- High current capability
- High Reliability
- High surge current capability
- Glass passivated chip junction
- Solder dip 275 °C max. 7 s, per JESD 22-B106

Mechanical Data

- **Package:** DO-204AL(DO-41)
Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity:** Color band denotes cathode end

■Maximum Ratings (T_a=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	HER101 G	HER102 G	HER103 G	HER104 G	HER105 G	HER106 G	HER107 G	HER108 G
Device marking code			HER101 G	HER102 G	HER103 G	HER104 G	HER105 G	HER106 G	HER107 G	HER108 G
Repetitive Peak Reverse Voltage	V _{RRM}	V	50	100	200	300	400	600	800	1000
Average Forward Current @60Hz sine wave, Resistance load, T _a =75°C	I _O	A	1.0							
Surge(Non-repetitive)Forward Current @60Hz Half-sine wave, 1 cycle, T _a =25°C	I _{FSM}	A	30							
Storage Temperature	T _{stg}	°C	-55 ~+150							
Junction Temperature	T _j	°C	-55~+150							

■Electrical Characteristics (T_a=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	HER101 G	HER102 G	HER103 G	HER104 G	HER105 G	HER106 G	HER107 G	HER108 G
Maximum instantaneous forward voltage drop per diode	V _{FM}	V	IFM=1.0A	1.0			1.3		1.7		
Maximum DC reverse current at rated DC blocking voltage per diode	I _{RRM1}	μA	T _a =25°C	2.5							
	I _{RRM2}		T _a =125°C	150							
Reverse Recovery time	t _{rr}	ns	I _F =0.5A I _R =1A I _{RR} =0.25A	50					75		
Typical junction capacitance	C _j	pF	Measured at 1MHZ and Applied Reverse Voltage of 4.0 V.D.C.	20					15		

■Thermal Characteristics (T_a=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	HER101G	HER102G	HER103G	HER104G	HER105G	HER106G	HER107G	HER108G
Thermal Resistance(Typical)	R _{θJA}	°C/W	60							



HER101G THRU HER108G

■ Ordering Information (Example)

PREFERRED P/N	PACKAGE CODE	UNIT WEIGHT(g)	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
HER101G~HER108G	D1	Approximate 0.30	5000	5000	50000	Tape
HER101G~HER108G	C1	Approximate 0.30	1000	1000	50000	Bulk

■ Characteristics (Typical)

FIG.1: I_o - T_a Curve

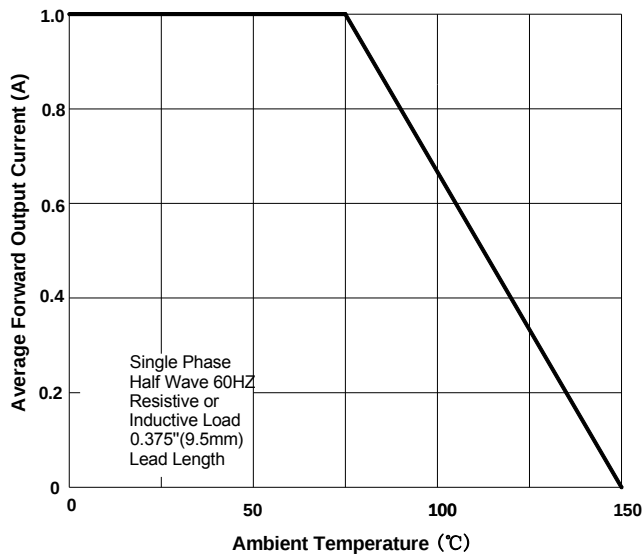


FIG.2: Surge Forward Current Capability

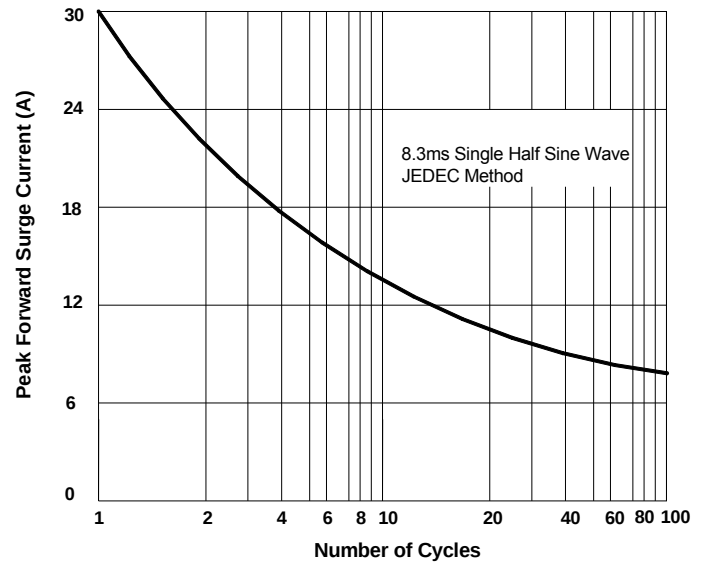


FIG.3: Forward Voltage

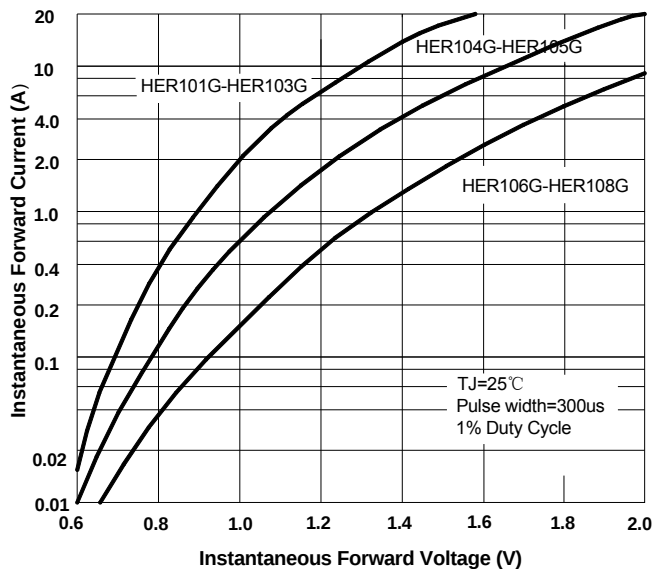
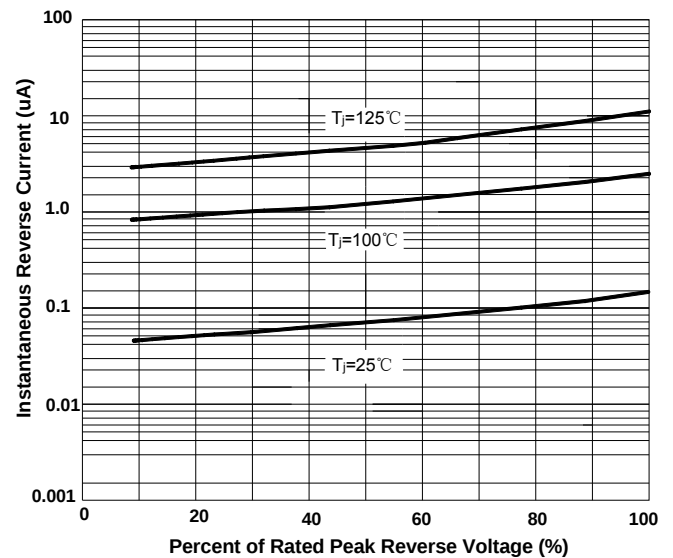


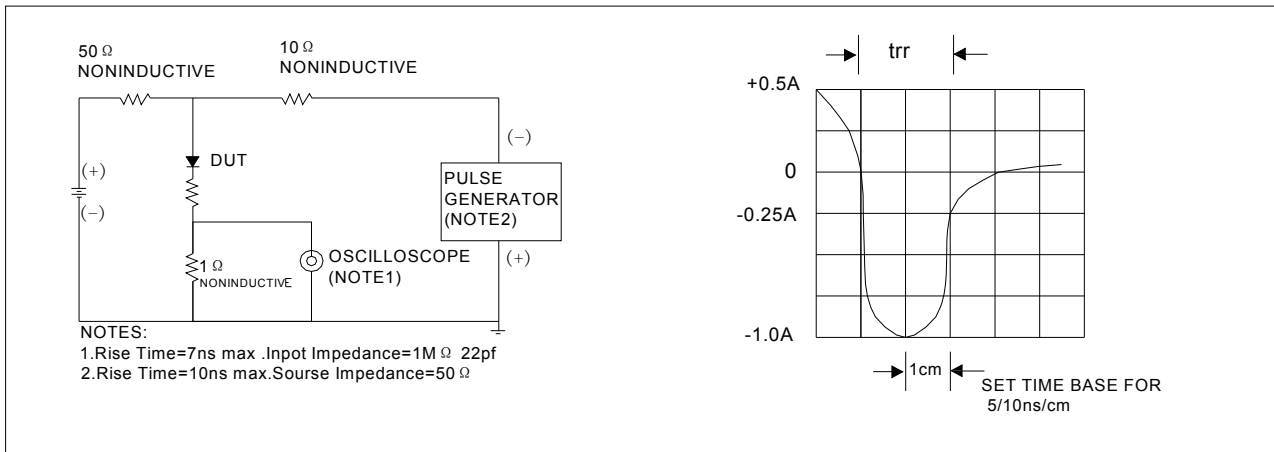
FIG.4: Typical Reverse Characteristics



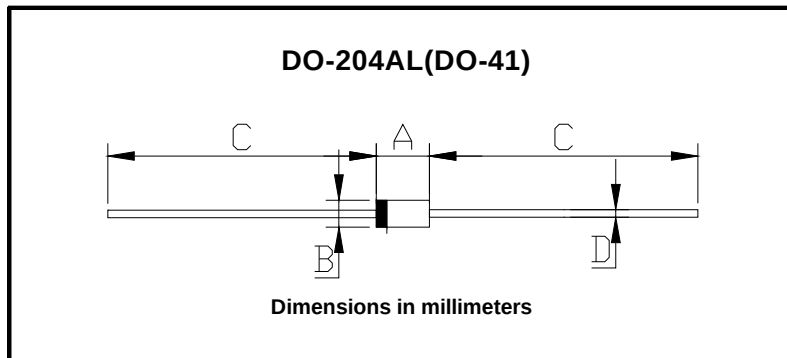


HER101G THRU HER108G

FIG.5: Diagram of circuit and Testing wave form of reverse recovery time



■ Outline Dimensions



DO-204AL(DO-41)		
Dim	Min	Max
A	4.22	5.21
B	2.03	2.72
C	25.4	/
D	0.69	0.86



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